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Vishay Semiconductors

Power Silicon Rectifier Diodes, (Stud Version), 35 A, 40 A, 60 A



DO-203AB (DO-5)

PRODUCT SUMMARY					
I _{F(AV)}	35 A, 40 A, 60 A				
Package	DO-203AB (DO-5)				
Circuit configuration	Single diode				

FEATURES

- · Low leakage current series
- · Good surge current capability up to 1000 A
- Material categorization: for definitions of compliance please see www.vishav.com/doc?99912



MAJOR RATINGS AND CHARACTERISTICS							
PARAMETER	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS	
1		35 ⁽¹⁾	35 ⁽¹⁾	40 (1)	60 ⁽¹⁾	Α	
I _{F(AV)}	T _C	140 ⁽¹⁾	140 ⁽¹⁾	150 ⁽¹⁾	140 ⁽¹⁾	°C	
1	50 Hz	480	380	765	860	А	
I _{FSM}	60 Hz	500 ⁽¹⁾	400 (1)	800 (1)	900 (1)		
I ² t	50 Hz	1140	730	2900	3700	A ² s	
1-1	60 Hz	1040	670	2650	3400	A-S	
I ² √t		16 100	10 300	41 000	52 500	A²√s	
V _{RRM}	Range	50 to 600 ⁽¹⁾	700 to 1000 ⁽¹⁾	50 to 600 ⁽¹⁾	50 to 600 ⁽¹⁾	V	
Tı		-65 to +200	-65 to +200	-65 to +200	-65 to +200	°C	

Note

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS					
TYPE NUMBER	1		V _{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE (T _J = -65 °C to +200 °C ⁽²⁾) V	V _{RM} , MAXIMUM DIRECT REVERSE VOLTAGE (T _J = -65 °C to +200 °C ⁽²⁾) V	
VS-1N1183	VS-1N1183A	VS-1N2128A	50 ⁽¹⁾	50 ⁽¹⁾	
VS-1N1184	VS-1N1184A	VS-1N2129A	100 (1)	100 ⁽¹⁾	
VS-1N1185	VS-1N1185A	VS-1N2130A	150 ⁽¹⁾	150 ⁽¹⁾	
VS-1N1186	VS-1N1186A	VS-1N2131A	200 (1)	200 (1)	
VS-1N1187	VS-1N1187A	VS-1N2133A	300 (1)	300 ⁽¹⁾	
VS-1N1188	VS-1N1188A	VS-1N2135A	400 (1)	400 (1)	
VS-1N1189	VS-1N1189A	VS-1N2137A	500 (1)	500 ⁽¹⁾	
VS-1N1190	VS-1N1190A	VS-1N2138A	600 (1)	600 ⁽¹⁾	
VS-1N3765			700 (1)	700 ⁽¹⁾	
VS-1N3766			800 (1)	800 ⁽¹⁾	
VS-1N3767			900 (1)	900 (1)	
VS-1N3768			1000 (1)	1000 (1)	

Notes

- Basic type number indicates cathode to case. For anode to case, add "R" to part number, e.g., 1N1188R, 1N3766R, 1N1186RA, 1N2135RA

 (1) JEDEC® registered values
- $^{(2)}$ For 1N1183 Series and 1N3765 Series $T_C = -65$ °C to +190 °C

⁽¹⁾ JEDEC® registered values



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FORWARD CONDUCTION	ON							
PARAMETER	SYMBOL	TEST CONDITIONS		1N1183	1N3765	1N1183A	1N2128A	UNITS
Maximum average forward curre	nt ,	1-phase operation, 180° sinusoidal conduction		35 ⁽¹⁾	35 ⁽¹⁾	40 ⁽¹⁾	60 ⁽¹⁾	Α
at case temperature	I _{F(AV)}			140 ⁽¹⁾	140 ⁽¹⁾	150 ⁽¹⁾	140 ⁽¹⁾	°C
		Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with rated V _{RRM} applied	480	380	765	860	A
Maximum peak one cycle		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		500 ⁽¹⁾	400 (1)	800 (1)	900 (1)	
non-repetitive surge current	I _{FSM}	Half cycle 50 Hz sine wave or 6 ms rectangular pulse	Following any rated load condition and with ½ V _{RRM} applied following surge = 0	570	455	910	1000	
		Half cycle 60 Hz sine wave or 5 ms rectangular pulse		595	475	950	1050	
Maximum I ² t for fusing		t = 10 ms	With rated V_{RRM} applied following surge, initial $T_J = T_J$ maximum	1140	730	2900	3700	- A ² s
	⊢ l²t	t = 8.3 ms		1040	670	2650	3400	
Maximum I ² t for individual	- 1 ² t	t = 10 ms	With V _{RRM} = 0 following surge,	1610	1030	4150	5250	
device fusing	ng initial	initial $T_J = T_J$ maximum	1470	940	3750	4750		
Maximum l²√t for individual device fusing	I²√t (2)	t = 0.1 to 10 ms, V _{RRM} = 0 following surge		16 100	10 300	41 500	52 500	A²√s
Maximum peak forward voltage	V _{FM}	T _J = 25 °C		1.7 (1)	1.8 ⁽¹⁾	1.3 ⁽¹⁾	1.3 (1)	V
at maximum forward current (I _{FN}) VFM			110	110	126	188	Α
V _{RRM} = 70)	Maximum rated $I_{F(AV)}$ and T_{C}		-	5.0 ⁽¹⁾	-	-	
$V_{RRM} = 80$)			-	4.0 (1)	-	-	mA
Maximum average reverse current $V_{RRM} = 900$	I _{R(AV)}			-	3.0 (1)	-	-	
V _{RRM} = 100	0			-	2.0 (1)	-	-	
		Maximum rated I _{F(AV)} , V _{RRM} and T _C		10 ⁽¹⁾	-	2.5 ⁽¹⁾	10 ⁽¹⁾	

Notes

(1) JEDEC® registered values

⁽²⁾ I^2t for time $t_x = I^2\sqrt{t} \times \sqrt{t_x}$



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THERMAL AND MECHANICAL SPECIFICATIONS								
PARAMETER	SYMBOL	TEST CONDITIONS	1N1183	1N3765	1N1183A	1N2128A	UNITS	
Maximum operating case temperature range	T _C		-65 to +190 ⁽¹⁾ -65 to +2			+200	့င	
Maximum storage temperature range	T _{Stg}		-65 to	-65 to +175 ⁽¹⁾ -65 to		+200		
Maximum internal thermal resistance, junction to case	R _{thJC}	DC operation	1.0	1.00 (1)		0.65 (1)	°C/W	
Thermal resistance, case to sink	R _{thCS}	Mounting surface, smooth, flat and greased	0.25		C/VV			
		Not lubricated thread, tighting on nut (2)		3.4	4 (30)			
Maximum allowable		Lubricated thread, tighting on nut (2)		2.3	3 (20)		N·m	
mounting torque (+ 0 %, - 10 %)		Not lubricated thread, tighting on hexagon (3)	4.2 (37)		(lbf·in)			
		Lubricated thread, tighting on hexagon (3)	3.2 (28)					
Annuavimete weight					17		g	
Approximate weight				0.6			oz.	
Case style		JEDEC®		DO	-203AB (DC)-5)		

Notes

- (1) JEDEC registered values®
- (2) Recommended for pass-through holes
- (3) Recommended for holed threaded heatsinks

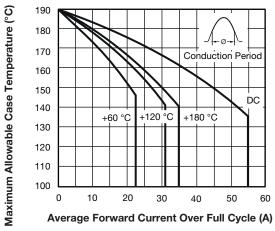


Fig. 1 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N1183 and 1N3765 Series

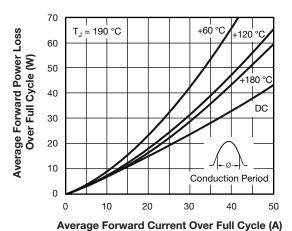


Fig. 2 - Typical Low Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series



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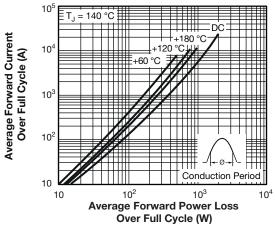


Fig. 3 - Typical High Level Forward Power Loss vs. Average Forward Current (Sinusoidal Current Waveform), 1N1183 and 1N3765 Series

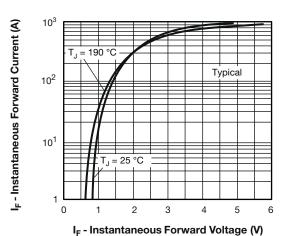


Fig. 4 - Typical Forward Voltage vs. Forward Current, 1N1183 and 1N3765 Series

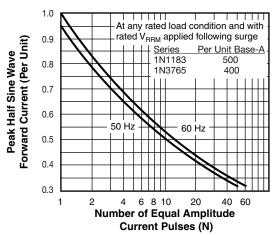
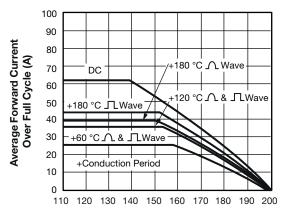
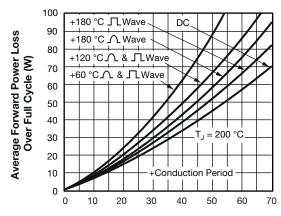


Fig. 5 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183 and 1N3765 Series



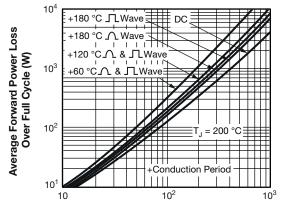
Maximum Allowable CaseTemperature (°C)

Fig. 6 - Average Forward Current vs. Maximum Allowable Case Temperature, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 7 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N1183A Series



Average Forward Current Over Full Cycle (A)

Fig. 8 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N1183A Series



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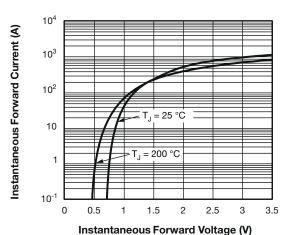


Fig. 9 - Maximum Forward Voltage vs. Forward Current, 1N1183A Series

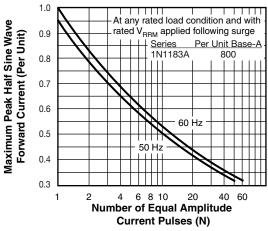


Fig. 10 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N1183A Series

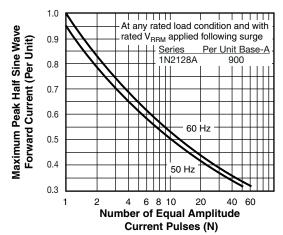
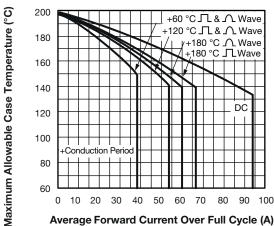


Fig. 11 - Maximum Non-Repetitive Surge Current vs. Number of Current Pulses, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 12 - Maximum Allowable Case Temperature vs. Average Forward Current, 1N2128A Series

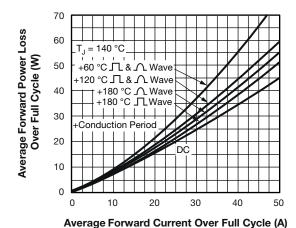
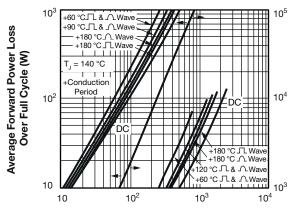


Fig. 13 - Maximum Low Level Forward Power Loss vs. Average Forward Current, 1N2128A Series



Average Forward Current Over Full Cycle (A)

Fig. 14 - Maximum High Level Forward Power Loss vs. Average Forward Current, 1N2128A Series

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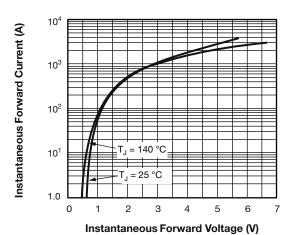


Fig. 15 - Maximum Forward Voltage vs. Forward Current, 1N2128A Series

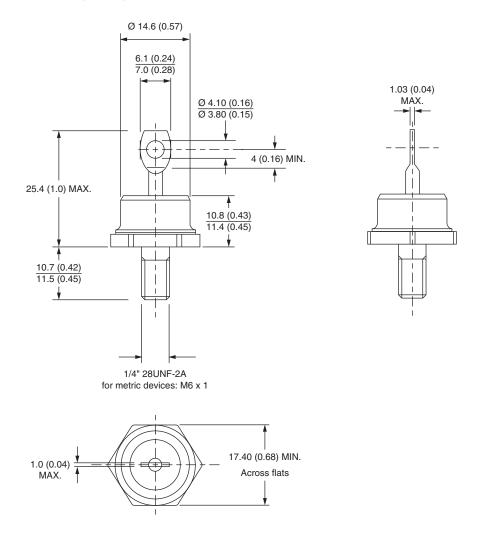
LINKS TO RELATED DOCUMENTS				
Dimensions	www.vishay.com/doc?95360			



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DO-203AB (DO-5) for 1N1183, 1N3765, 1N1183A, 1N2128A, 1N3208 Series

DIMENSIONS in millimeters (inches)





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Revision: 02-Oct-12 Document Number: 91000